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What are **Embedded - System On Chip (SoC)**?

System On Chip (SoC) integrates multiple functions of a computer or electronic system onto a single chip. Unlike traditional multi-chip solutions. SoCs combine a central

Details	
Product Status	Active
Architecture	MCU, FPGA
Core Processor	Dual ARM® Cortex®-A9 MPCore™ with CoreSight™
Flash Size	-
RAM Size	64KB
Peripherals	DMA, POR, WDT
Connectivity	CANbus, EBI/EMI, Ethernet, I ² C, MMC/SD/SDIO, SPI, UART/USART, USB OTG
Speed	800MHz
Primary Attributes	FPGA - 85K Logic Elements
Operating Temperature	-40°C ~ 100°C (TJ)
Package / Case	484-FBGA
Supplier Device Package	484-UBGA (19x19)
Purchase URL	https://www.e-xfl.com/product-detail/intel/5cseba5u19i7n

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong



This datasheet describes the electrical characteristics, switching characteristics, configuration specifications, and I/O timing for Cyclone® V devices.

Cyclone V devices are offered in commercial and industrial grades. Commercial devices are offered in -C6 (fastest), -C7, and -C8 speed grades. Industrial grade devices are offered in the -I7 speed grade. Automotive devices are offered in the -A7 speed grade.

Cyclone V SoC devices are also offered in a low-power variant, as indicated by the L power option in the device part number. These devices have 30% static power reduction for devices with 25K LE and 40K LE, and 20% static power reduction for devices with 85K LE and 110K LE. Note that the L power option devices are only available in –I7 speed grade, and have the equivalent operating conditions and timing specifications as the standard –I7 speed grade devices.

Table 1. Low Power Variants

Density	Ordering Part Number (OPN)	Static Power Reduction
25K LE	5CSEBA2U19I7LN	30%
	5CSEBA2U23I7LN	
	5CSXFC2C6U23I7LN	
40K LE	5CSEBA4U19I7LN	
	5CSEBA4U23I7LN	
	5CSXFC4C6U23I7LN	
85K LE	5CSEBA5U19I7LN	20%
	5CSEBA5U23I7LN	
	5CSXC5C6U23I7LN	
		continued

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Recommended Operating Conditions

Table 4. Recommended Operating Conditions for Cyclone V Devices

This table lists the steady-state voltage values expected from Cyclone V devices. Power supply ramps must all be strictly monotonic, without plateaus.

Symbol	Description	Condition	Minimum ⁽²⁾	Typical	Maximum ⁽²⁾	Unit
V _{CC}	Core voltage, periphery circuitry power supply, transceiver physical coding sublayer (PCS)	Devices without internal scrubbing feature	1.07	1.1	1.13	V
	power supply, and transceiver PCI Express* (PCIe*) hard IP digital power supply	Devices with internal scrubbing feature (with SC suffix) (3)	1.12	1.15	1.18	V
V _{CC_AUX}	Auxiliary supply	_	2.375	2.5	2.625	V
V _{CCPD} ⁽⁴⁾	I/O pre-driver power supply	3.3 V	3.135	3.3	3.465	V
		3.0 V	2.85	3.0	3.15	V
		2.5 V	2.375	2.5	2.625	V
V _{CCIO}	I/O buffers power supply	3.3 V	3.135	3.3	3.465	V
		3.0 V	2.85	3.0	3.15	V
		2.5 V	2.375	2.5	2.625	V
		1.8 V	1.71	1.8	1.89	V
		1.5 V	1.425	1.5	1.575	V
		1.35 V	1.283	1.35	1.418	V
		1.25 V	1.19	1.25	1.31	V
		1.2 V	1.14	1.2	1.26	V
						continued

⁽²⁾ The power supply value describes the budget for the DC (static) power supply tolerance and does not include the dynamic tolerance requirements. Refer to the PDN tool for the additional budget for the dynamic tolerance requirements.

⁽³⁾ The SEU internal scrubbing feature is available for Cyclone V E, GX, SE, and SX devices with the "SC" suffix in the part number. For device availability and ordering, contact your local Intel sales representatives.

 $^{^{(4)}}$ V_{CCPD} must be 2.5 V when V_{CCIO} is 2.5, 1.8, 1.5, 1.35, 1.25, or 1.2 V. V_{CCPD} must be 3.0 V when V_{CCIO} is 3.0 V. V_{CCPD} must be 3.3 V when V_{CCIO} is 3.3 V.

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Symbol	Description	Condition	Minimum ⁽²⁾	Typical	Maximum ⁽²⁾	Unit
V _{CCPGM}	Configuration pins power supply	3.3 V	3.135	3.3	3.465	V
		3.0 V	2.85	3.0	3.15	V
		2.5 V	2.375	2.5	2.625	V
		1.8 V	1.71	1.8	1.89	V
V _{CCA_FPLL} ⁽⁵⁾	PLL analog voltage regulator power supply	_	2.375	2.5	2.625	V
V _{CCBAT} ⁽⁶⁾	Battery back-up power supply (For design security volatile key register)	_	1.2	_	3.0	V
V _I	DC input voltage	_	-0.5	_	3.6	V
Vo	Output voltage	_	0	_	V _{CCIO}	V
T _J	Operating junction temperature	Commercial	0	_	85	°C
		Industrial	-40	_	100	°C
		Automotive	-40	_	125	°C
t _{RAMP} ⁽⁷⁾	Power supply ramp time	Standard POR	200µs	_	100ms	_
		Fast POR	200µs	_	4ms	_

⁽²⁾ The power supply value describes the budget for the DC (static) power supply tolerance and does not include the dynamic tolerance requirements. Refer to the PDN tool for the additional budget for the dynamic tolerance requirements.

 $^{^{(5)}}$ PLL digital voltage is regulated from $V_{CCA\ FPLL}$.

⁽⁶⁾ If you do not use the design security feature in Cyclone V devices, connect V_{CCBAT} to a 1.5-V, 2.5-V, or 3.0-V power supply. Cyclone V power-on reset (POR) circuitry monitors V_{CCBAT} . Cyclone V devices do not exit POR if V_{CCBAT} is not powered up.

⁽⁷⁾ This is also applicable to HPS power supply. For HPS power supply, refer to t_{RAMP} specifications for standard POR when HPS_PORSEL = 0 and t_{RAMP} specifications for fast POR when HPS PORSEL = 1.



Table 9. OCT Calibration Accuracy Specifications for Cyclone V Devices

Calibration accuracy for the calibrated on-chip series termination (R_S OCT) and on-chip parallel termination (R_T OCT) are applicable at the moment of calibration. When process, voltage, and temperature (PVT) conditions change after calibration, the tolerance may change.

Symbol	Description	Condition (V)	Ca	alibration Accura	cy	Unit
			-C6	-I7, -C7	-C8, -A7	
25-Ω R _S	Internal series termination with calibration (25- Ω setting)	V _{CCIO} = 3.0, 2.5, 1.8, 1.5, 1.2	±15	±15	±15	%
50-Ω R _S	Internal series termination with calibration (50- Ω setting)	V _{CCIO} = 3.0, 2.5, 1.8, 1.5, 1.2	±15	±15	±15	%
34- Ω and 40- Ω R _S	Internal series termination with calibration (34- Ω and 40- Ω setting)	V _{CCIO} = 1.5, 1.35, 1.25, 1.2	±15	±15	±15	%
48-Ω, 60-Ω, and 80-Ω R_S	Internal series termination with calibration (48- Ω , 60- Ω , and 80- Ω setting)	V _{CCIO} = 1.2	±15	±15	±15	%
50-Ω R _T	Internal parallel termination with calibration (50- Ω setting)	V _{CCIO} = 2.5, 1.8, 1.5, 1.2	-10 to +40	-10 to +40	-10 to +40	%
20-Ω, 30-Ω, 40-Ω,60-Ω, and 120-Ω R_T	Internal parallel termination with calibration (20- Ω , 30- Ω , 40- Ω , 60- Ω , and 120- Ω setting)	V _{CCIO} = 1.5, 1.35, 1.25	-10 to +40	-10 to +40	-10 to +40	%
60- Ω and 120- Ω R _T	Internal parallel termination with calibration (60- Ω and 120- Ω setting)	V _{CCIO} = 1.2	-10 to +40	-10 to +40	-10 to +40	%
25-Ω R _{S_left_shift}	Internal left shift series termination with calibration (25- Ω R _{S_left_shift} setting)	V _{CCIO} = 3.0, 2.5, 1.8, 1.5, 1.2	±15	±15	±15	%



Table 14. Internal Weak Pull-Up Resistor Values for Cyclone V Devices

Symbol	Description	Condition (V) ⁽¹⁶⁾	Value ⁽¹⁷⁾	Unit
R _{PU}	Value of the I/O pin pull-up resistor before and during configuration, as well	V _{CCIO} = 3.3 ±5%	25	kΩ
	as user mode if you have enabled the programmable pull-up resistor option.	V _{CCIO} = 3.0 ±5%	25	kΩ
		V _{CCIO} = 2.5 ±5%	25	kΩ
		V _{CCIO} = 1.8 ±5%	25	kΩ
		V _{CCIO} = 1.5 ±5%	25	kΩ
		V _{CCIO} = 1.35 ±5%	25	kΩ
		V _{CCIO} = 1.25 ±5%	25	kΩ
		V _{CCIO} = 1.2 ±5%	25	kΩ

Related Information

Cyclone V Device Family Pin Connection Guidelines

Provides more information about the pins that support internal weak pull-up and internal weak pull-down features.

I/O Standard Specifications

Tables in this section list the input voltage (V_{IH} and V_{IL}), output voltage (V_{OH} and V_{OL}), and current drive characteristics (I_{OH} and I_{OL}) for various I/O standards supported by Cyclone V devices.

You must perform timing closure analysis to determine the maximum achievable frequency for general purpose I/O standards.

 $^{^{(16)}}$ Pin pull-up resistance values may be lower if an external source drives the pin higher than V_{CCIO} .

 $^{^{(17)}}$ Valid with $\pm 10\%$ tolerances to cover changes over PVT.



Single-Ended I/O Standards

Table 15. Single-Ended I/O Standards for Cyclone V Devices

I/O Standard		V _{CCIO} (V)		١	/ _{IL} (V)	V _{IH}	(V)	V _{OL} (V)	V _{OH} (V)	I _{OL} (18)	I _{OH} ⁽¹⁸⁾ (mA)
	Min	Тур	Max	Min	Max	Min	Max	Max	Min	(mA)	(mA)
3.3-V LVTTL	3.135	3.3	3.465	-0.3	0.8	1.7	3.6	0.45	2.4	4	-4
3.3-V LVCMOS	3.135	3.3	3.465	-0.3	0.8	1.7	3.6	0.2	V _{CCIO} - 0.2	2	-2
3.0-V LVTTL	2.85	3	3.15	-0.3	0.8	1.7	3.6	0.4	2.4	2	-2
3.0-V LVCMOS	2.85	3	3.15	-0.3	0.8	1.7	3.6	0.2	V _{CCIO} - 0.2	0.1	-0.1
3.0-V PCI*	2.85	3	3.15	_	0.3 × V _{CCIO}	0.5 × V _{CCIO}	V _{CCIO} + 0.3	0.1 × V _{CCIO}	0.9 × V _{CCIO}	1.5	-0.5
3.0-V PCI-X	2.85	3	3.15	_	0.35 × V _{CCIO}	0.5 × V _{CCIO}	V _{CCIO} + 0.3	0.1 × V _{CCIO}	0.9 × V _{CCIO}	1.5	-0.5
2.5 V	2.375	2.5	2.625	-0.3	0.7	1.7	3.6	0.4	2	1	-1
1.8 V	1.71	1.8	1.89	-0.3	0.35 × V _{CCIO}	0.65 × V _{CCIO}	V _{CCIO} + 0.3	0.45	V _{CCIO} - 0.45	2	-2
1.5 V	1.425	1.5	1.575	-0.3	0.35 × V _{CCIO}	0.65 × V _{CCIO}	V _{CCIO} + 0.3	0.25 × V _{CCIO}	0.75 × V _{CCIO}	2	-2
1.2 V	1.14	1.2	1.26	-0.3	0.35 × V _{CCIO}	0.65 × V _{CCIO}	V _{CCIO} + 0.3	0.25 × V _{CCIO}	0.75 × V _{CCIO}	2	-2

Single-Ended SSTL, HSTL, and HSUL I/O Reference Voltage Specifications

Table 16. Single-Ended SSTL, HSTL, and HSUL I/O Reference Voltage Specifications for Cyclone V Devices

I/O Standard		V _{CCIO} (V) V _{REF} (V) V _{TT} (V)							
	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max
SSTL-2 Class I, II	2.375	2.5	2.625	0.49 × V _{CCIO}	0.5 × V _{CCIO}	0.51 × V _{CCIO}	V _{REF} - 0.04	V _{REF}	V _{REF} + 0.04
SSTL-18 Class I, II	1.71	1.8	1.89	0.833	0.9	0.969	V _{REF} - 0.04	V _{REF}	V _{REF} + 0.04
		'							continued

To meet the I_{OL} and I_{OH} specifications, you must set the current strength settings accordingly. For example, to meet the 3.3-V LVTTL specification (4 mA), you should set the current strength settings to 4 mA. Setting at lower current strength may not meet the I_{OL} and I_{OH} specifications in the datasheet.



Transceiver Performance Specifications

Transceiver Specifications for Cyclone V GX, GT, SX, and ST Devices

Table 21. Reference Clock Specifications for Cyclone V GX, GT, SX, and ST Devices

Symbol/Description	Condition	Transceiv	er Speed G	rade 5 ⁽³⁰⁾	Transce	iver Speed	Grade 6	Transce	iver Speed	Grade 7	Unit
		Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	
Supported I/O standards		1.2	2 V PCML, 1.	5 V PCML, 2.	5 V PCML, [Differential L	VPECL ⁽³¹⁾ , H	CSL, and LV	DS		
Input frequency from REFCLK input pins ⁽³²⁾	_	27	_	550	27	_	550	27	_	550	MHz
Rise time	Measure at ±60 mV of differential signal ⁽³³⁾	_	_	400	_	_	400	_	_	400	ps
Fall time	Measure at ±60 mV of differential signal ⁽³³⁾	_	_	400	_	_	400	_	_	400	ps
Duty cycle	_	45	_	55	45	_	55	45	_	55	%
Peak-to-peak differential input voltage	_	200	_	2000	200	_	2000	200	_	2000	mV
Spread-spectrum modulating clock frequency	PCIe	30	_	33	30	_	33	30	_	33	kHz
Spread-spectrum downspread	PCIe	_	0 to - 0.5%	_	_	0 to - 0.5%	_	_	0 to - 0.5%	_	_
On-chip termination resistors	_	_	100	_	_	100	_	_	100	_	Ω
										co	ntinued

⁽³⁰⁾ Transceiver Speed Grade 5 covers specifications for Cyclone V GT and ST devices.

⁽³¹⁾ Differential LVPECL signal levels must comply to the minimum and maximum peak-to-peak differential input voltage specified in this table.

⁽³²⁾ The reference clock frequency must be \geq 307.2 MHz to be fully compliance to CPRI transmit jitter specification at 6.144 Gbps. For more information about CPRI 6.144 Gbps, refer to the *Transceiver Protocol Configurations in Cyclone V Devices* chapter.

 $^{^{(33)}}$ REFCLK performance requires to meet transmitter REFCLK phase noise specification.

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Symbol/Description	Symbol/Description Condition				Transceiver Speed Grade 6			Transceiver Speed Grade 7			Unit
		Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	
Programmable ppm detector ⁽⁴⁶⁾	_			±62.5	5, 100, 125,	200, 250, 3	00, 500, and	1000			ppm
Run length	_	_	_	200	_	_	200	_	_	200	UI
Programmable equalization AC and DC gain	AC gain setting = 0 to 3 ⁽⁴⁷⁾ DC gain setting = 0 to 1		X, and ST De	se at Data Revices and Cl DC Gain for	TLE Respons	e at Data Ra	$tes \leq 3.25$ (Gbps across	Supported A		dB

Table 24. Transmitter Specifications for Cyclone V GX, GT, SX, and ST Devices

Symbol/Description	Condition	Transceiv	er Speed G	rade 5 ⁽³⁰⁾	Transce	iver Speed	Grade 6	Transce	Unit		
		Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	
Supported I/O standards					1.5 V	PCML	•				
Data rate	_	614	_	5000/614 4 ⁽³⁵⁾	614	_	3125	614	_	2500	Mbps
V _{OCM} (AC coupled)	_	_	650	_	_	650	_	_	650	_	mV
Differential on-chip	85-Ω setting	_	85	_	_	85	_	_	85	_	Ω
termination resistors	100-Ω setting	_	100	_	_	100	_	_	100	_	Ω
	120-Ω setting	_	120	_	_	120	_	_	120	_	Ω
	150-Ω setting	_	150	_	_	150	_	_	150	_	Ω
		•				•	•			co	ntinued

 $^{^{(45)}}$ $t_{LTR_LTD_manual}$ is the time the receiver CDR must be kept in lock to reference (LTR) mode after the rx_is_lockedtoref signal goes high when the CDR is functioning in the manual mode.

 $^{^{(46)}}$ The rate matcher supports only up to ± 300 parts per million (ppm).

⁽⁴⁷⁾ The Intel Quartus Prime software allows AC gain setting = 3 for design with data rate between 614 Mbps and 1.25 Gbps only.



Typical TX V_{OD} Setting for Cyclone V Transceiver Channels with termination of 100 Ω

Table 27. Typical TX V_{OD} Setting for Cyclone V Transceiver Channels with termination of 100 Ω

Symbol	V _{OD} Setting ⁽⁴⁸⁾	V _{OD} Value (mV)	V _{OD} Setting ⁽⁴⁸⁾	V _{OD} Value (mV)
OD differential peak-to-peak typical	6(49)	120	34	680
	7 ⁽⁴⁹⁾	140	35	700
	8(49)	160	36	720
	9	180	37	740
	10	200	38	760
	11	220	39	780
	12	240	40	800
	13	260	41	820
	14	280	42	840
	15	300	43	860
	16	320	44	880
	17	340	45	900
	18	360	46	920
	19	380	47	940
	20	400	48	960
	21	420	49	980
	22	440	50	1000
	23	460	51	1020
	24	480	52	1040
		•		continu

⁽⁴⁸⁾ Convert these values to their binary equivalent form if you are using the dynamic reconfiguration mode for PMA analog controls.

⁽⁴⁹⁾ Only valid for data rates \leq 5 Gbps.



Transceiver Compliance Specification

The following table lists the physical medium attachment (PMA) specification compliance of all supported protocol for Cyclone V GX, GT, SX, and ST devices. For more information about the protocol parameter details and compliance specifications, contact your Intel Sales Representative.

Table 29. Transceiver Compliance Specification for All Supported Protocol for Cyclone V GX, GT, SX, and ST Devices

Protocol	Sub-protocol	Data Rate (Mbps)
PCIe	PCIe Gen1	2,500
	PCIe Gen2 ⁽⁵⁰⁾	5,000
	PCIe Cable	2,500
XAUI	XAUI 2135	3,125
Serial RapidIO® (SRIO)	SRIO 1250 SR	1,250
	SRIO 1250 LR	1,250
	SRIO 2500 SR	2,500
	SRIO 2500 LR	2,500
	SRIO 3125 SR	3,125
	SRIO 3125 LR	3,125
	SRIO 5000 SR	5,000
	SRIO 5000 MR	5,000
	SRIO 5000 LR	5,000
Common Public Radio Interface (CPRI)	CPRI E6LV	614.4
	CPRI E6HV	614.4
	CPRI E6LVII	614.4
		continued

⁽⁵⁰⁾ For PCIe Gen2 sub-protocol, Intel recommends increasing the V_{CCE_GXBL} and V_{CCL_GXBL} typical value from 1.1 V to 1.2 V for Cyclone V GT and ST FPGA systems which ensure full compliance to the PCIe Gen2 transmit jitter specification. For more information about the maximum full duplex channels recommended in Cyclone V GT and ST devices under this condition, refer to the *Transceiver Protocol Configurations in Cyclone V Devices* chapter.

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Protocol	Sub-protocol	Data Rate (Mbps)
	CPRI E12LV	1,228.8
	CPRI E12HV	1,228.8
	CPRI E12LVII	1,228.8
	CPRI E24LV	2,457.6
	CPRI E24LVII	2,457.6
	CPRI E30LV	3,072
	CPRI E30LVII	3,072
	CPRI E48LVII ⁽⁵¹⁾	4,915.2
	CPRI E60LVII ⁽⁵¹⁾	6,144
Gbps Ethernet (GbE)	GbE 1250	1,250
OBSAI	OBSAI 768	768
	OBSAI 1536	1,536
	OBSAI 3072	3,072
Serial digital interface (SDI)	SDI 270 SD	270
	SDI 1485 HD	1,485
	SDI 2970 3G	2,970
VbyOne	VbyOne 3750	3,750
HiGig+	HIGIG 3750	3,750

Related Information

• PCIe Supported Configurations and Placement Guidelines

Provides more information about the maximum full duplex channels recommended in Cyclone V GT and ST devices which require full compliance to the PCIe Gen2 transmit jitter specification.

⁽⁵¹⁾ For CPRI E48LVII and E60LVII, Intel recommends increasing the V_{CCE_GXBL} and V_{CCL_GXBL} typical value from 1.1 V to 1.2 V for full compliance to CPRI transmit jitter specification at 4.9152 Gbps (Cyclone V GT and ST devices) and 6.144 Gbps (Cyclone V GT and ST devices for CPRI 6.144 Gbps, refer to the *Transceiver Protocol Configurations in Cyclone V Devices* chapter.

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Symbol	Condition		-C6			-C7, -I7			-C8, -A7		Unit
		Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	
	SERDES factor J = 1 to 2, uses DDR registers	(65)	_	(66)	(65)	_	(66)	(65)	_	(66)	Mbps
Emulated Differential I/O Standards with Three External Output Resistor Networks- f _{HSDR} (data rate) ⁽⁶⁷⁾	SERDES factor J = 4 to 10	(65)	_	640	(65)	-	640	(65)	_	550	Mbps
Emulated Differential I/O Standards with One External Output Resistor Network - f _{HSDR} (data rate)	SERDES factor J = 4 to 10	(65)	_	170	(65)	_	170	(65)	_	170	Mbps
t _{x Jitter} -True Differential I/O Standards ⁽⁶⁷⁾	Total Jitterfor Data Rate, 600 Mbps – 840 Mbps	_	_	350	_	_	380	_	_	500	ps
	Total Jitter for Data Rate < 600Mbps	_	_	0.21	_	_	0.23	_	_	0.30	UI
t _{x Jitter} -Emulated Differential I/O Standards with Three External Output Resistor Networks	Total Jitter for Data Rate < 640Mbps	_	_	500	_	_	500	_	_	500	ps
t _{x Jitter} -Emulated Differential I/O Standards with One External Output Resistor Network	Total Jitter for Data Rate < 640Mbps	_	_	0.15	_	_	0.15	_	_	0.15	UI
t _{DUTY}	TX output clock duty cycle for both True and	45	50	55	45	50	55	45	50	55	%
'					·	1	1		1	cont	inued

The maximum ideal data rate is the SERDES factor (J) \times PLL max output frequency (f_{out}), provided you can close the design timing and the signal integrity simulation is clean. You can estimate the achievable maximum data rate by performing link timing closure analysis. You must consider the board skew margin, transmitter delay margin, and receiver sampling margin to determine the maximum data rate supported.

⁽⁶⁷⁾ You must calculate the leftover timing margin in the receiver by performing link timing closure analysis. You must consider the board skew margin, transmitter channel-to-channel skew, and receiver sampling margin to determine the leftover timing margin.



SD/MMC Timing Characteristics

Table 46. Secure Digital (SD)/MultiMediaCard (MMC) Timing Requirements for Cyclone V Devices

After power up or cold reset, the Boot ROM uses drvsel = 3 and smplsel = 0 to execute the code. At the same time, the SD/MMC controller enters the Identification Phase followed by the Data Phase. During this time, the value of interface output clock SDMMC_CLK_OUT changes from a maximum of 400 kHz (Identification Phase) up to a maximum of 12.5 MHz (Data Phase), depending on the internal reference clock SDMMC_CLK and the CSEL setting. The value of SDMMC_CLK is based on the external oscillator frequency and has a maximum value of 50 MHz.

After the Boot ROM code exits and control is passed to the preloader, software can adjust the value of drvsel and smplsel via the system manager. drvsel can be set from 1 to 7 and smplsel can be set from 0 to 7. While the preloader is executing, the values for SDMMC_CLK and SDMMC_CLK_OUT increase to a maximum of 200 MHz and 50 MHz respectively.

Symbol	Description	Min	Max	Unit
T _{sdmmc_clk} (internal reference clock)	SDMMC_CLK clock period (Identification mode)	20	_	ns
	SDMMC_CLK clock period (Default speed mode)	5	_	ns
	SDMMC_CLK clock period (High speed mode)	5	_	ns
T _{sdmmc_clk_out} (interface output clock)	SDMMC_CLK_OUT clock period (Identification mode)	2500	_	ns
	SDMMC_CLK_OUT clock period (Default speed mode)	40	_	ns
	SDMMC_CLK_OUT clock period (High speed mode)	20	_	ns
T _{dutycycle}	SDMMC_CLK_OUT duty cycle	45	55	%
T _d	SDMMC_CMD/SDMMC_D output delay	(T _{sdmmc_clk} × drvsel)/2 - 1.23	(T _{sdmmc_clk} × drvsel)/2 + 1.69 ⁽⁷⁰⁾	ns
T _{su}	Input setup time	$1.05 - (T_{\text{sdmmc_clk}} \times \text{smplsel})/2$	_	ns
T _h	Input hold time	$(T_{sdmmc_clk} \times smplsel)/2$ (71)	_	ns

 $^{^{(70)}}$ drvsel is the drive clock phase shift select value.

 $^{^{(71)}}$ smplsel is the sample clock phase shift select value.



Table 49. RGMII RX Timing Requirements for Cyclone V Devices

Symbol	Description	Min	Тур	Unit
T _{clk} (1000Base-T)	RX_CLK clock period	_	8	ns
T _{clk} (100Base-T)	RX_CLK clock period	_	40	ns
T _{clk} (10Base-T)	RX_CLK clock period	_	400	ns
T _{su}	RX_D/RX_CTL setup time	1	_	ns
T _h	RX_D/RX_CTL hold time	1	_	ns

Figure 12. RGMII RX Timing Diagram

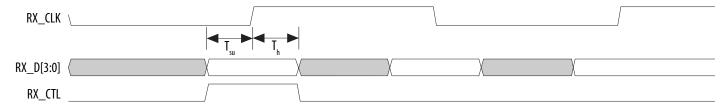
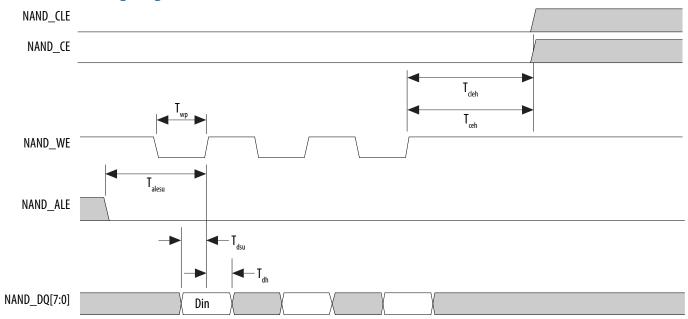


Table 50. Management Data Input/Output (MDIO) Timing Requirements for Cyclone V Devices

Symbol	Description	Min	Тур	Max	Unit
T _{clk}	MDC clock period	_	400	_	ns
T _d	MDC to MDIO output data delay	10	_	20	ns
T _s	Setup time for MDIO data	10	_	_	ns
T _h	Hold time for MDIO data	0	-	_	ns



Figure 17. NAND Data Write Timing Diagram



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Symbol	Description	Min	Max	Unit
t _{JPCO}	JTAG port clock to output	_	11 ⁽⁷⁶⁾	ns
t _{JPZX}	JTAG port high impedance to valid output	_	14 ⁽⁷⁶⁾	ns
t _{JPXZ}	JTAG port valid output to high impedance	_	14 ⁽⁷⁶⁾	ns

FPP Configuration Timing

DCLK-to-DATA[] Ratio (r) for FPP Configuration

Fast passive parallel (FPP) configuration requires a different DCLK-to-DATA[] ratio when you turn on encryption or the compression feature.

Depending on the DCLK-to-DATA[] ratio, the host must send a DCLK frequency that is r times the DATA[] rate in byte per second (Bps) or word per second (Wps). For example, in FPP $\times 16$ where the r is 2, the DCLK frequency must be 2 times the DATA[] rate in Wps.

Cyclone V devices use additional clock cycles to decrypt and decompress the configuration data. If the DCLK-to-DATA[] ratio is greater than 1, at the end of configuration, you can only stop the DCLK (DCLK-to-DATA[] ratio - 1) clock cycles after the last data is latched into the Cyclone V device.

Table 57. DCLK-to-DATA[] Ratio for Cyclone V Devices

Configuration Scheme	Encryption	Compression	DCLK-to-DATA[] Ratio (r)
FPP (8-bit wide)	Off	Off	1
	On	Off	1
	Off	On	2
	On	On	2
FPP (16-bit wide)	Off	Off	1
			continued

⁽⁷⁶⁾ A 1-ns adder is required for each VCCIO voltage step down from 3.0 V. For example, tJPCO= 13 ns if VCCIO of the TDO I/O bank = 2.5 V, or 14 ns if it equals 1.8 V.



Active Serial (AS) Configuration Timing

Table 60. AS Timing Parameters for AS ×1 and ×4 Configurations in Cyclone V Devices

The minimum and maximum numbers apply to both the internal oscillator and CLKUSR when either one is used as the clock source for device configuration.

The t_{CF2ST0} , t_{CF2ST0} , t_{CF2ST0} , t_{CF2ST0} , t_{CF2ST1} timing parameters are identical to the timing parameters for passive serial (PS) mode listed in PS Timing Parameters for Cyclone V Devices table. You can obtain the t_{CF2ST1} value if you do not delay configuration by externally holding nSTATUS low.

Symbol	Parameter	Minimum	Maximum	Unit
t _{co}	DCLK falling edge to the AS_DATAO/ASDO output	_	2	ns
t _{SU}	Data setup time before the falling edge on DCLK	1.5	_	ns
t _{DH} ⁽⁸⁶⁾	Data hold time after the falling edge on DCLK	2.5 ⁽⁸⁷⁾ /2.9 ⁽⁸⁸⁾	_	ns
t _{CD2UM}	CONF_DONE high to user mode	175	437	μs
t _{CD2CU}	CONF_DONE high to CLKUSR enabled	4 × maximum DCLK period	_	_
t _{CD2UMC}	CONF_DONE high to user mode with CLKUSR option on	$t_{CD2CU} + (T_{init} \times CLKUSR period)$	_	_
T _{init}	Number of clock cycles required for device initialization	8,576	_	Cycles

Related Information

- Passive Serial (PS) Configuration Timing on page 74
- AS Configuration Timing
 Provides the AS configuration timing waveform.
- AN822: Intel FPGA Configuration Device Migration Guideline

⁽⁸⁶⁾ Note: To evaluate the data setup (t_{SU}) and data hold time (t_{DH}) slack on your board in order to ensure you are meeting the t_{SU} and t_{DH} requirement, you are recommended to follow the guideline in the "Evaluating Data Setup and Hold Timing Slack" chapter in AN822: Intel FPGA Configuration Device Migration Guideline.

⁽⁸⁷⁾ Specification for -6 speed grade

⁽⁸⁸⁾ Specification for -7 and -8 speed grade



Configuration Files

Table 64. Uncompressed .rbf Sizes for Cyclone V Devices

Use this table to estimate the file size before design compilation. Different configuration file formats, such as a hexadecimal file (.hex) or tabular text file (.ttf) format, have different file sizes.

For the different types of configuration file and file sizes, refer to the Intel Quartus Prime software. However, for a specific version of the Intel Quartus Prime software, any design targeted for the same device has the same uncompressed configuration file size.

The IOCSR raw binary file (.rbf) size is specifically for the Configuration via Protocol (CvP) feature.

Variant	Member Code	Configuration .rbf Size (bits)	IOCSR .rbf Size (bits)	Recommended EPCQ Serial Configuration Device ⁽⁹⁴⁾
Cyclone V E ⁽⁹⁵⁾	A2	21,061,280	275,608	EPCQ64
	A4	21,061,280	275,608	EPCQ64
	A5	33,958,560	322,072	EPCQ128
	A7	56,167,552	435,288	EPCQ128
	A9	102,871,776	400,408	EPCQ256
Cyclone V GX	C3	14,510,912	320,280	EPCQ32
	C4	33,958,560	322,072	EPCQ128
	C5	33,958,560	322,072	EPCQ128
	C7	56,167,552	435,288	EPCQ128
	C9	102,871,776	400,408	EPCQ256
Cyclone V GT	D5	33,958,560	322,072	EPCQ128
	D7	56,167,552	435,288	EPCQ128
	D9	102,871,776	400,408	EPCQ256
Cyclone V SE (95)	A2	33,958,560	322,072	EPCQ128
				continued

⁽⁹⁴⁾ The recommended EPCQ serial configuration devices are able to store more than one image.

⁽⁹⁵⁾ No PCIe hard IP, configuration via protocol (CvP) is not supported in this family.



Variant	Member Code		Active Seria	l ⁽⁹⁶⁾		Fast Passive Pa	rallel ⁽⁹⁷⁾
		Width	DCLK (MHz)	Minimum Configuration Time (ms)	Width	DCLK (MHz)	Minimum Configuration Time (ms)
	A9	4	100	257	16	125	51
Cyclone V GX	C3	4	100	36	16	125	7
	C4	4	100	85	16	125	17
	C5	4	100	85	16	125	17
	C7	4	100	140	16	125	28
	C9	4	100	257	16	125	51
Cyclone V GT	D5	4	100	85	16	125	17
	D7	4	100	140	16	125	28
	D9	4	100	257	16	125	51
Cyclone V SE	A2	4	100	85	16	125	17
	A4	4	100	85	16	125	17
	A5	4	100	140	16	125	28
	A6	4	100	140	16	125	28
Cyclone V SX	C2	4	100	85	16	125	17
	C4	4	100	85	16	125	17
	C5	4	100	140	16	125	28
	C6	4	100	140	16	125	28
Cyclone V ST	D5	4	100	140	16	125	28
	D6	4	100	140	16	125	28

 $^{^{(96)}\,}$ DCLK frequency of 100 MHz using external CLKUSR.

⁽⁹⁷⁾ Maximum FPGA FPP bandwidth may exceed bandwidth available from some external storage or control logic.

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Programmable Output Buffer Delay

Table 69. Programmable Output Buffer Delay for Cyclone V Devices

This table lists the delay chain settings that control the rising and falling edge delays of the output buffer.

You can set the programmable output buffer delay in the Intel Quartus Prime software by setting the **Output Buffer Delay Control** assignment to either positive, negative, or both edges, with the specific values stated here (in ps) for the **Output Buffer Delay** assignment.

Symbol	Parameter	Typical	Unit
D _{OUTBUF}	Rising and/or falling edge delay	0 (default)	ps
		50	ps
		100	ps
		150	ps

Glossary

Table 70. Glossary

Term	Definition
Differential I/O standards	Receiver Input Waveforms
	continued